EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1089	257/77.cds.	US-PGPUB; USPAT	OR	ON	2008/02/22 12:05
82	72	257/77.ccls. and (impurity or dop\$3) with low near10 (surface or top)	US-PGPUB; USPAT	OR	ON	2008/02/22 12:08
S3	81	257/77.ccls. and (impurity or dop\$3) near3 profile	US-PGPUB; USPAT	OR	ON	2008/02/22 12:28
S4	11	257/77.ccls. and graded near8 (impurity or dop\$3) near3 profile	US-PGPUB; USPAT	OR	ON	2008/02/22 12:29
S5	35	257/77.ccls. and drift adj layer near10 epitaxial	US-PGPUB; USPAT	OR	ON	2008/02/22 15:40
S6	0	sigle adj step near5 ion adj implantation and MOS	US-PGPUB; USPAT	OR	ON	2008/02/22 16:29
S7	17	single adj step near5 ion adj implantation and MOS	US-PGPUB; USPAT	OR	ON	2008/02/22 16:29
S8	28	single adj step with ion adj implantation and MOS	US-PGPUB; USPAT	OR	ON	2008/02/22 16:33
S9	28	(single adj step or single- step) with ion adj implantation and MOS	US-PGPUB; USPAT	OR	ON	2008/02/22 16:33
S10	2	"20040119076"	US-PGPUB; USPAT	OR	ON	2008/09/18 18:13
S11	1	(silicon adj carbide or epitaxial) with (single-step or single adj step) near5 ion near implant\$5 and implantation adj energy and @ad<"20040227"	US-PGPUB; USPAT	OR	ON	2008/09/18 18:20
S12	13	(single-step or single adj step) near5 ion near implant\$5 and implantation adj energy and @ad<"20040227"	US-PGPUB; USPAT	OR	ON	2008/09/18 18:31
S13	20	constant near5 implantation adj energy and @ad<"20040227"	US-PGPUB; USPAT	OR	ON	2008/09/18 18:37
S14	10	accumulation same mobility near10 (improv\$3 or increas\$3) and silicon adj carbide and @ad<"20040227"	US-PGPUB; USPAT	OR	ON	2009/01/07 17:56

S15	4	("20040238883"	US-PGPUB;	OR	ON	2009/01/07
3		"6228725" "6455892"	USPAT;			18:17
		"6784492").PN.	USOCR			

1/7/2009 8:29:27 PM

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